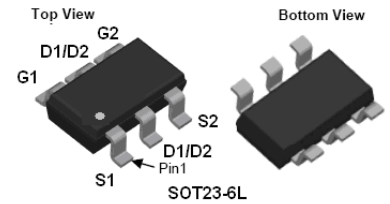


Features

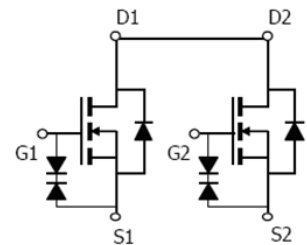
- Dual N-Channel, 2.5V Logic Level Control
- Low on-resistance $R_{DS(on)}$ @ $V_{GS}=2.5\text{ V}$
- Fast Switching
- ESD Protection HBM 2.5KV
- High Effective
- Pb-free lead plating; RoHS compliant; Halogen-Free

V_{DS}	20	V
$R_{DS(on),TYP}$ @ $V_{GS}=4.5\text{ V}$	18	m Ω
$R_{DS(on),TYP}$ @ $V_{GS}=2.5\text{ V}$	25	m Ω
I_D	6	A

SOT23-6L



Part ID	Package Type	Marking	Tape and reel information
VS6808DH	SOT23-6L	VS05	3000pcs/reel



Maximum ratings, at $T_A=25\text{ }^\circ\text{C}$, unless otherwise specified

Symbol	Parameter	Rating	Unit
$V_{(BR)DSS}$	Drain-Source breakdown voltage	20	V
I_S	Diode continuous forward current	$T_C=25\text{ }^\circ\text{C}$ 1	A
I_D	Continuous drain current @ $V_{GS}=4.5\text{ V}$	$T_C=25\text{ }^\circ\text{C}$ 6	A
		$T_C=100\text{ }^\circ\text{C}$ 4	A
I_{DM}	Pulse drain current tested ①	$T_C=25\text{ }^\circ\text{C}$ 24	A
P_D	Maximum power dissipation	$T_C=25\text{ }^\circ\text{C}$ 1.25	W
V_{GS}	Gate-Source voltage	± 8	V
T_{STG}, T_J	Storage and junction temperature range	-55 to 150	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	Typical	Unit
$R_{\theta JL}$	Thermal Resistance, Junction-to-Lead	60	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	100	$^\circ\text{C/W}$



Typical Electrical Characteristics

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
Static Electrical Characteristics @ T_J = 25°C (unless otherwise stated)						
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	20	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current(Tc=25°C)	V _{DS} =20V, V _{GS} =0V	--	--	1	μA
	Zero Gate Voltage Drain Current(Tc=125°C)	V _{DS} =20V, V _{GS} =0V	--	--	100	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±8V, V _{DS} =0V	--	--	±10	μA
V _{GS(TH)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	0.4	0.8	1.2	V
R _{DS(ON)}	Drain-Source On-State Resistance②	V _{GS} =4.5V, I _D =6A	--	18	23	mΩ
R _{DS(ON)}	Drain-Source On-State Resistance②	V _{GS} =2.5V, I _D =5A	--	25	32	mΩ
R _{DS(ON)}	Drain-Source On-State Resistance②	V _{GS} =1.8V, I _D =2A	--	44	55	mΩ
Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise stated)						
C _{iss}	Input Capacitance	V _{DS} =10V, V _{GS} =0V, f=1MHz	--	410	--	pF
C _{oss}	Output Capacitance		--	90	--	pF
C _{rss}	Reverse Transfer Capacitance		--	80	--	pF
Q _g	Total Gate Charge	V _{DS} =10V, I _D =6A, V _{GS} =4.5V	--	8.4	--	nC
Q _{gs}	Gate-Source Charge		--	2.4	--	nC
Q _{gd}	Gate-Drain Charge		--	3.3	--	nC
Switching Characteristics						
t _{d(on)}	Turn-on Delay Time	V _{DS} =10V, I _D =6A, R _G =3Ω, V _{GS} =4.5V	--	6.5	--	ns
t _r	Turn-on Rise Time		--	8	--	ns
t _{d(off)}	Turn-Off Delay Time		--	35	--	ns
t _f	Turn-Off Fall Time		--	9.1	--	ns
Source- Drain Diode Characteristics @ T_J = 25°C (unless otherwise stated)						
V _{SD}	Forward on voltage	I _{SD} =1.6A, V _{GS} =0V	--	0.8	1.2	V
t _{rr}	Reverse Recovery Time	T _J =25°C, I _{sd} =1.6A, V _{GS} =0V	--	15	--	ns
Q _{rr}	Reverse Recovery Charge	di/dt=100A/μs	--	5.3	--	nC

NOTE:

- ① Repetitive rating; pulse width limited by max. junction temperature.
- ② Pulse width ≤ 300μs; duty cycle ≤ 2%.



Typical Characteristics

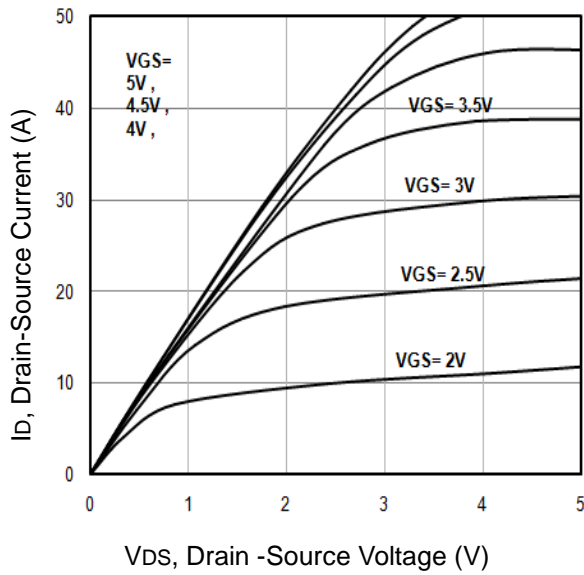


Fig1. Typical Output Characteristics

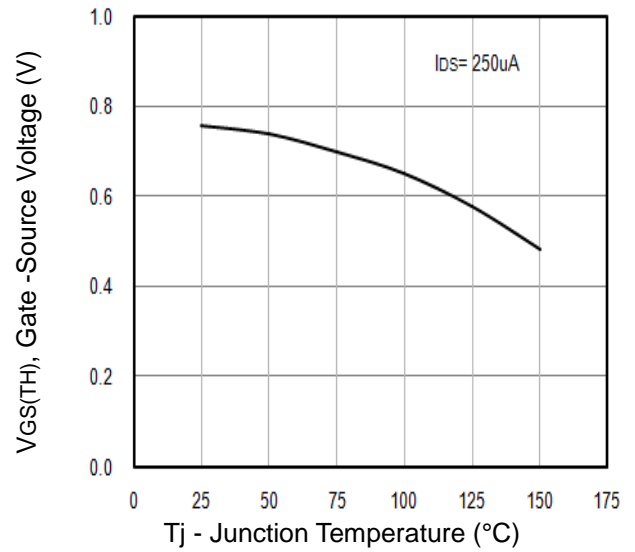


Fig2. Threshold Voltage Vs. Temperature

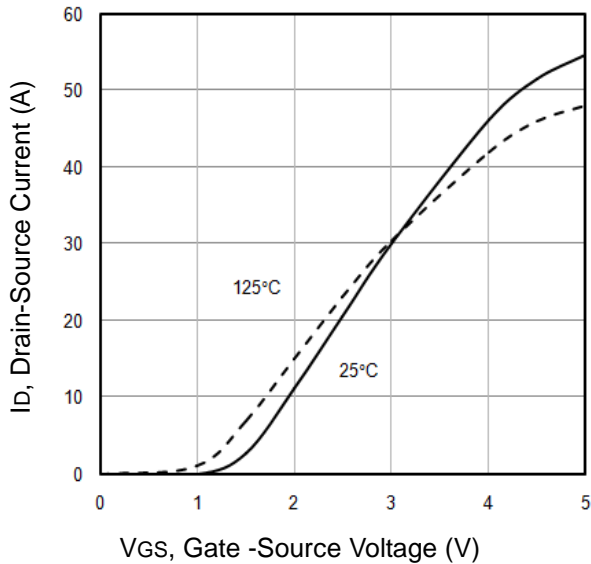


Fig3. Typical Transfer Characteristics

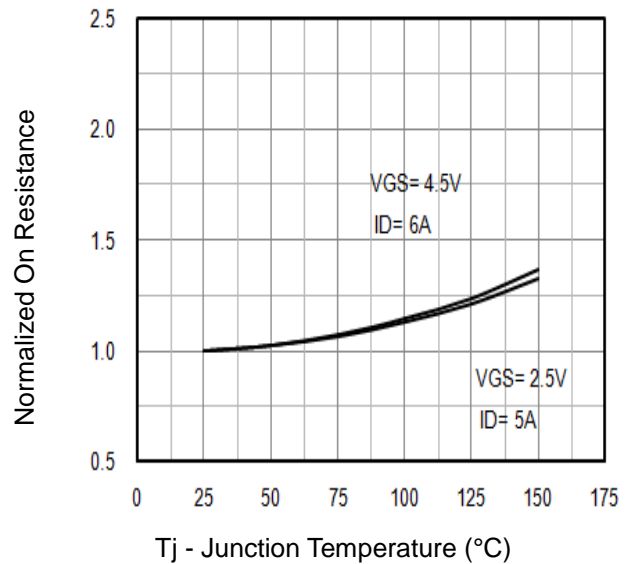


Fig4. Normalized On-Resistance Vs. Temperature

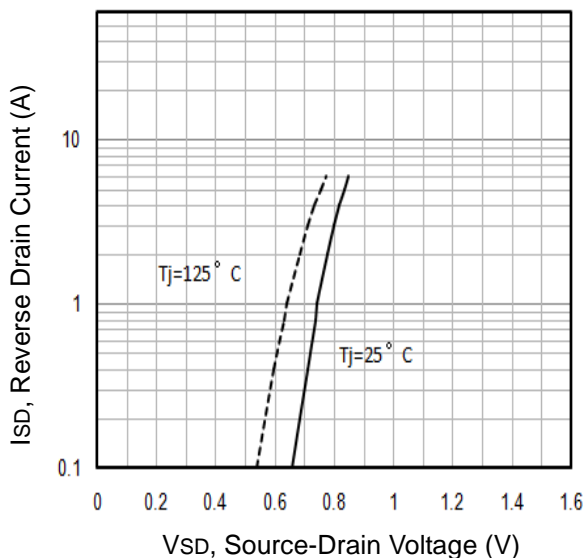


Fig5. Typical Source-Drain Diode Forward Voltage

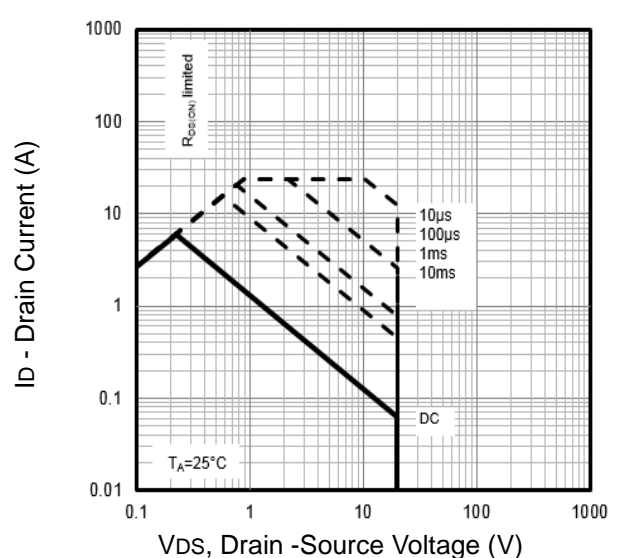


Fig6. Maximum Safe Operating Area

Typical Characteristics

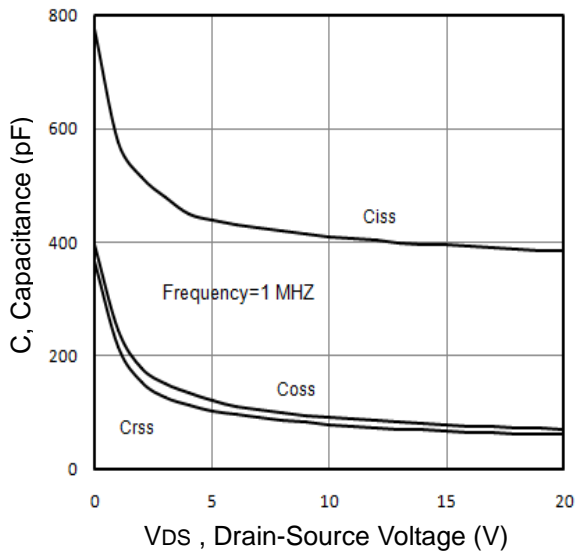


Fig7. Typical Capacitance Vs.Drain-Source Voltage

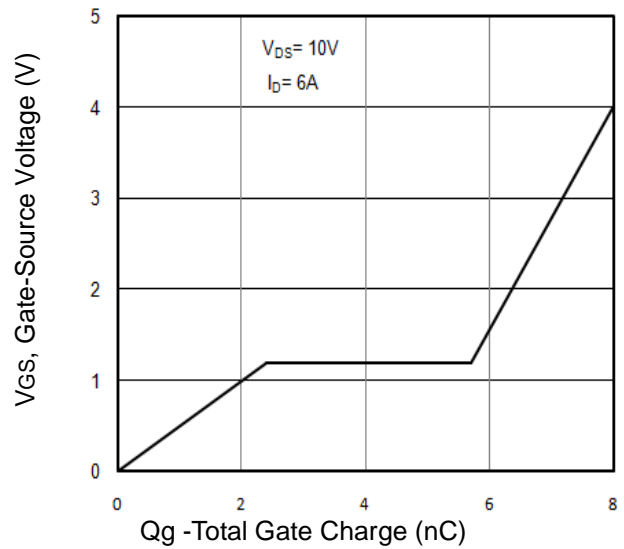


Fig8. Typical Gate Charge Vs.Gate-Source Voltage

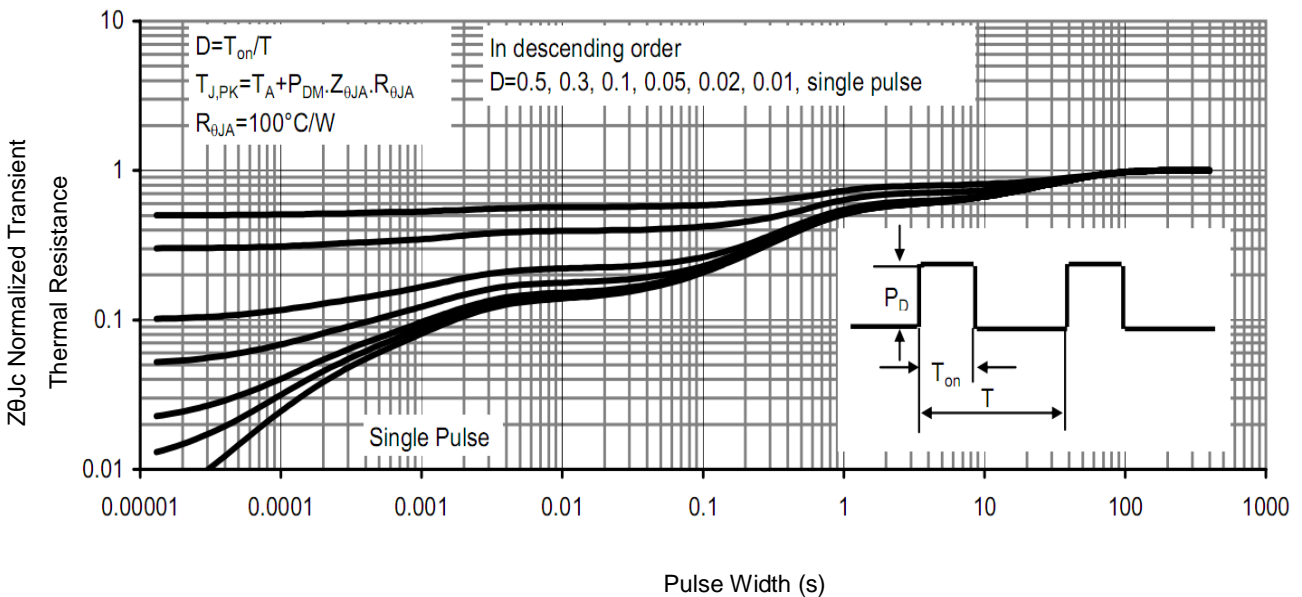


Fig9 . Normalized Maximum Transient Thermal Impedance

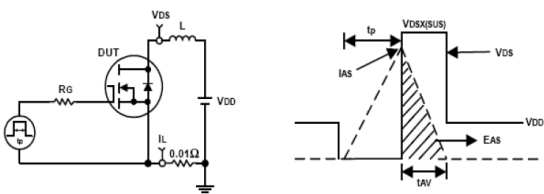


Fig10. Unclamped Inductive Test Circuit and waveforms

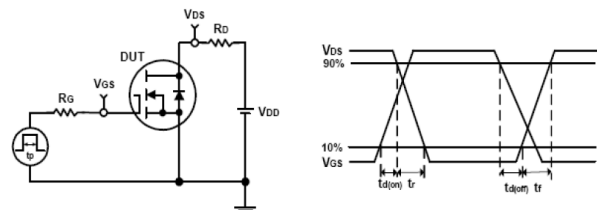
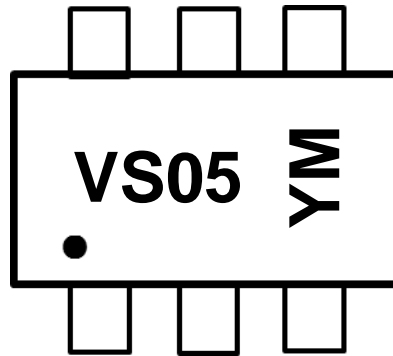


Fig11. Switching Time Test Circuit and waveforms



Marking Information

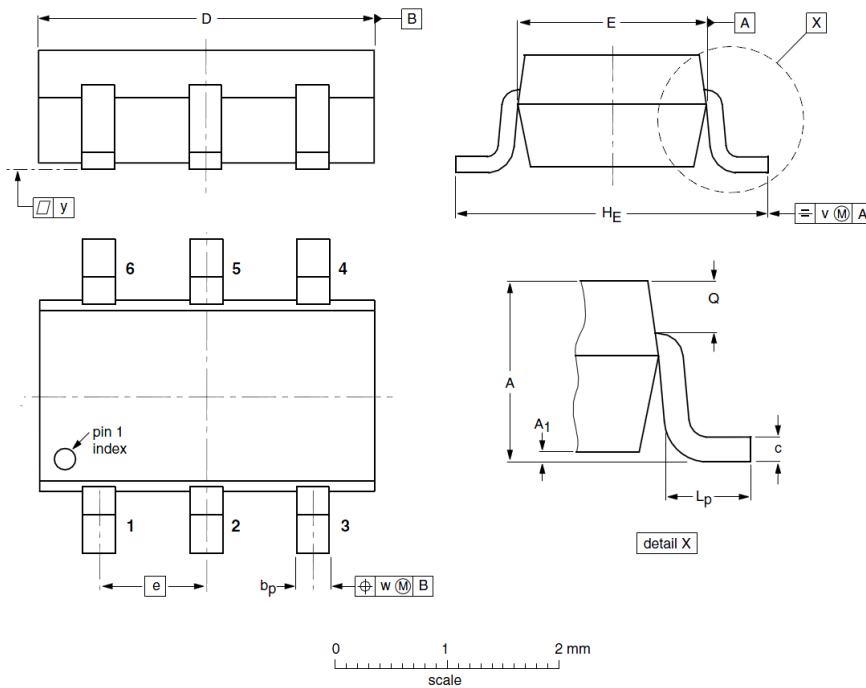


VS05: Part Number

YM: Date Code, Y means assembly year, M means assembly month



SOT23-6L Package Outline



Label	Dimensions (unit: mm)		
	Min	Typ	Max
A	0.90	1.07	1.45
bp	0.30	0.35	0.40
D	2.70	2.92	3.10
e	--	0.95	--
Lp	0.30	0.45	0.60
v	--	0.20	--
y	--	0.10	--
A1	0.01	0.05	0.15
c	0.10	0.15	0.22
E	1.30	1.55	1.70
HE	2.50	2.80	3.00
Q	0.23	0.29	0.33
w	--	0.20	--

Notes:

1. Follow JEDEC MS-012.
2. Dimension "D" does NOT include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.15mm per side.
3. Dimension "E" does NOT include interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.25mm per side.
4. Dimension "bp" does NOT include dambar protrusion. Allowable dambar protrusion shall be 0.1mm total in excess of "bp" dimension at maximum material condition. The dambar cannot be located on the lower radius of the foot.

Customer Service

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